

**Green Products** 

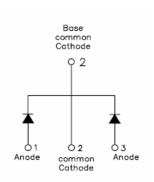
# MBR20100CT SCHOTTKY RECTIFIER

## **Applications:**

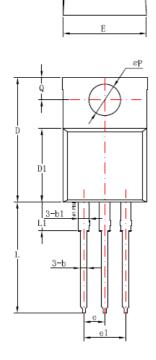
- · Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

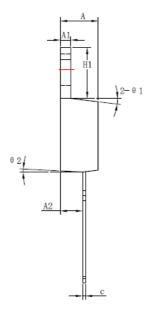
#### Features:

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



#### **Mechanical Dimensions: In mm**





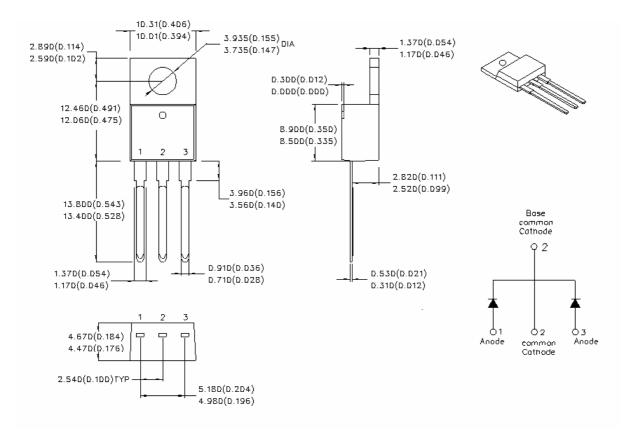
	Dimensions in				
Symbol	millimeters				
	Min	Typical	Max		
Α	4.42	4.57	4.72		
<b>A</b> 1	1.17	1.27	1.37		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1		1.27			
С	0.36	0.38	0.61		
D	14.94	15.24	15.54		
D1	8.85	9.00	9.15		
E	10.01	10.16	10.31		
е		2.54			
e1		5.06			
H1	6.04	6.24	6.44		
L	12.7	13.56	13.78		
L1		3.5			
ФР	3.74	3.84	4.04		
Q	2.54	2.74	2.94		
Θ1		7°			
Θ2		3°			
Θ3		4°			

#### OPTION1(HD)

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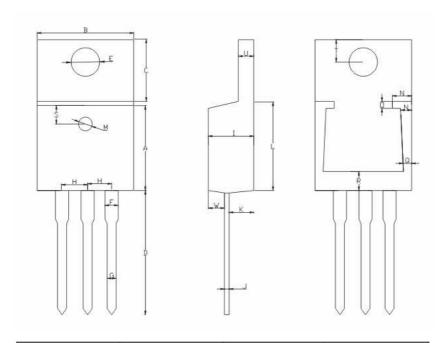


**OPTION 2(CJ)** 

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A:8.5±0.5	B: 9. 5±0. 5	C:6.4±0.5	D:14.1±1
E: 3, 84 ± 0, 03	F: 1.27±0.03	G:0.85±0.10	H:2.54±0.025
I:4.6±0.5	J:0.38±0.015	K:2.75±025	L:9.0±0.5
M: 1.5±0.05	N: 1.8±0.05	0:0.5±0.05	P:1.2±0.05
Q: 0. 9±0.05	R: 3. 2±0. 05	S:1.55±0.05	T:2.8±0.15
U: 1. 27 ± 0. 05	W: 1.27±0.03		

**OPTION 3(SR)** 

**TO-220AB** 



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#### **Marking Diagram:**



Where XXXXX is YYWWL

MBR = Device Type

20 = Forward Current (20A) 100 = Reverse Voltage (100V)

CT = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

### **Ordering Information:**

Device	Package Package	Shipping
MBR20100CT	TO-220AB	FOnce / tube
	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	100	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =105℃, rectangular wave form	20	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	150	А

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 10A, Pulse, T <sub>J</sub> = 25 °C	0.90	V
(per leg) *	$V_{F2}$	@ 10A, Pulse, T <sub>J</sub> = 125 °C	0.80	V
Max. Reverse Current at DC condition (per leg)	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}C$	1.0	mA
Max. Reverse Current (per leg) *	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125  ^{\circ}\text{C}$	6.0	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	300	pF
Typical Series Inductance (per leg)	L <sub>S</sub>	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

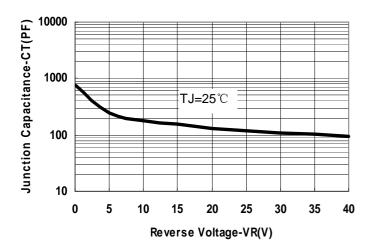
<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +150	°C
Max. Storage Temperature	$T_{stg}$	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

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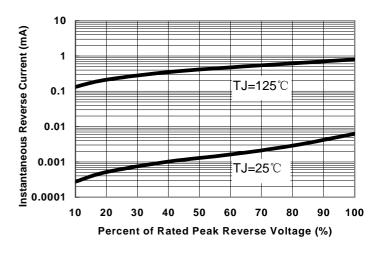


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

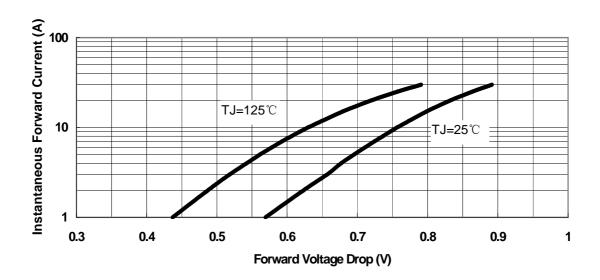


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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#### **MBR20100CT**

Technical Data
Data Sheet N0623, Rev. -

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